

SGM11108E SP8T High Power RF Switch

GENERAL DESCRIPTION

The SGM11108E is a single-pole/eight-throw (SP8T) antenna switch, which supports from 0.1GHz to 3GHz. The device features low insertion loss and high isolation, which make it suitable for 2G/3G/4G transmitting/receiving (TRx) applications. It also has the advantage of high linearity performance. The SGM11108E is not subject to cellular interference and is applied to multi-mode and multi-band LTE mobile phones.

The SGM11108E has the ability to integrate SP8T RF switch and GPIO controller on an SOI chip. Internal driver and decoder for switch control signals are offered by the GPIO controller, which makes it flexible in RF path band and routing selection.

No external DC blocking capacitors required on the RF paths as long as no external DC voltage is applied, which can save PCB area and cost.

The SGM11108E is available in a Green UTQFN-2×2-14L package.

APPLICATIONS

Receiving Band Switching and Pre-PA Switching 2G/3G/4G Transmitting/Receiving (TRx)

FEATURES

- Supply Voltage Range: 2.5V to 3.4V
- GPIO Controller
- Low Insertion Loss: 0.7dB (TYP) at 2.7GHz
- Operating Frequency Range: 0.1GHz to 3GHz
- High Isolation: 17dB (MIN) at 2.7GHz
- Advanced Silicon-On-Insulator (SOI) Process
- No External DC Blocking Capacitors Required
- Available in a Green UTQFN-2×2-14L Package

BLOCK DIAGRAM

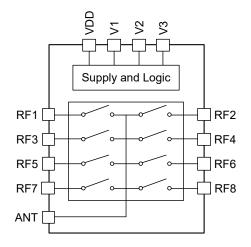


Figure 1. SGM11108E Block Diagram

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	MPERATURE ORDERING PACKAGE NUMBER MARKING		PACKING OPTION
SGM11108E	UTQFN-2×2-14L	-40°C to +85°C	SGM11108EYURB14G/TR	S007 XXXX	Tape and Reel, 3000

MARKING INFORMATION

NOTE: XXXX = Date Code and Trace Code.



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V _{DD}	3.6V
Control Voltage (V1, V2 and V3 Pins), Vctl	3.6V
RF Input Power, P _{IN}	37.5dBm
Junction Temperature	+150°C
Storage Temperature Range	-55°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	1000V

RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range	40°C to +85°C
Operating Frequency Range	0.1GHz to 3GHz
Supply Voltage, V _{DD}	2.5V to 3.4V
Control High Voltage, V _{CTL_H}	1.66V to 3.4V
Control Low Voltage, Vote I	0V to 0.45V

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

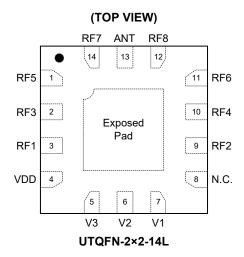
ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATION



PIN DESCRIPTION

PIN	NAME	FUNCTION
1	RF5	RF I/O Port 5.
2	RF3	RF I/O Port 3.
3	RF1	RF I/O Port 1.
4	VDD	DC Power Supply.
5	V3	DC Control Voltage 3.
6	V2	DC Control Voltage 2.
7	V1	DC Control Voltage 1.
8	N.C.	No Connection.
9	RF2	RF I/O Port 2.
10	RF4	RF I/O Port 4.
11	RF6	RF I/O Port 6.
12	RF8	RF I/O Port 8.
13	ANT	Antenna Port.
14	RF7	RF I/O Port 7.
Exposed Pad	GND	Ground. Exposed pad must be connected to ground.

LOGIC TRUTH TABLE

CC	ONTROL PI	NS	SWITCHED RF PATHS									
V1	V2	V3	RF1	RF2	RF3	RF4	RF5	RF6	RF7	RF8		
0	0	0	Insertion Loss	Isolation								
0	0	1	Isolation	Insertion Loss	Isolation	Isolation	Isolation	Isolation	Isolation	Isolation		
0	1	0	Isolation	Isolation	Insertion Loss	Isolation	Isolation	Isolation	Isolation	Isolation		
0	1	1	Isolation	Isolation	Isolation	Insertion Loss	Isolation	Isolation	Isolation	Isolation		
1	0	0	Isolation	Isolation	Isolation	Isolation	Insertion Loss	Isolation	Isolation	Isolation		
1	0	1	Isolation	Isolation	Isolation	Isolation	Isolation	Insertion Loss	Isolation	Isolation		
1	1	0	Isolation	Isolation	Isolation	Isolation	Isolation	Isolation	Insertion Loss	Isolation		
1	1	1	Isolation	Insertion Loss								

ELECTRICAL CHARACTERISTICS

 $(V_{DD} = 2.5 \text{V to } 3.4 \text{V}, T_A = +25 ^{\circ}\text{C}, P_{IN} = 0 \text{dBm}, 50 \Omega, \text{ typical values are at } V_{DD} = 2.8 \text{V}, \text{ unless otherwise noted.})$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
DC Specifications	•					•	
Supply Voltage	V_{DD}		2.5	2.8	3.4	V	
Supply Current	I _{DD}			40	80	μΑ	
Control Voltage	V _{CTL_H}	High	1.66	1.8	3.4	V	
Control Voltage	V _{CTL_L}	Low	0		0.45	\ \ \	
Control Current	I _{CTL}	V _{CTL} = 0V		3	8	μA	
Switching Time	t _{sw}	50% of control voltage to 90% of RF power		2	5	μs	
Turn-On Time	t _{on}	Time from V_{DD} = 0V to part on and RF at 90%		10	15	μs	
RF Specifications							
		0.1GHz to 1.0GHz		0.45	1.06		
Insertion Loss (ANT to All RF Ports)	IL	1.0GHz to 2.0GHz		0.55	1.11	dB	
(/ / /		2.0GHz to 2.7GHz		0.70	1.58		
		0.1GHz to 1.0GHz	21	42		dB	
Isolation (ANT to All RF Ports)	ISO	1.0GHz to 2.0GHz	20	35			
(2.0GHz to 2.7GHz	17	30			
		0.1GHz to 1.0GHz	25	30			
Input Return Loss (ANT to All RF Ports)	RL	1.0GHz to 2.0GHz	20	22		dB	
(/ / /		2.0GHz to 2.7GHz	15	20			
0.1dB Compression Point (ANT to All RF Ports)	P _{0.1dB}	0.1GHz to 3GHz		37.5		dBm	
2 nd Harmonics GSM LB	2f ₀	P _{IN} = 35dBm, 824MHz to 915MHz		90		dBc	
3 rd Harmonics GSM LB	3f ₀	P _{IN} = 35dBm, 824MHz to 915MHz		80		dBc	
2 nd Harmonics GSM HB	2f ₀	P _{IN} = 33dBm, 1710MHz to 1910MHz		90		dBc	
3 rd Harmonics GSM HB	3f ₀	P _{IN} = 33dBm, 1710MHz to 1910MHz		85		dBc	
2 nd Harmonics	2f ₀	P _{IN} = 26dBm, 0.1GHz to 2.7GHz		95		dBc	
3 rd Harmonics	3f ₀	P _{IN} = 26dBm, 0.1GHz to 2.7GHz		90		dBc	

TYPICAL APPLICATION CIRCUIT

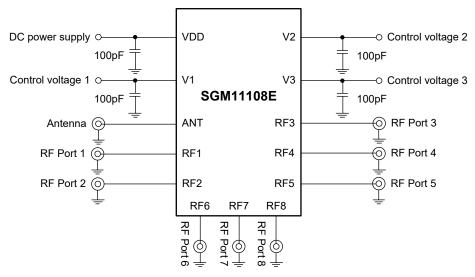


Figure 2. SGM11108E Typical Application Circuit

EVALUATION BOARD LAYOUT

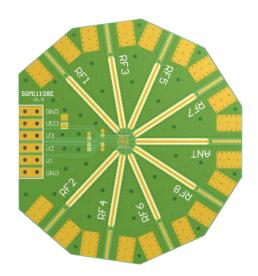


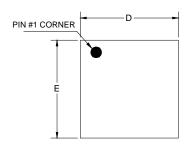
Figure 3. SGM11108E Evaluation Board Layout

REVISION HISTORY

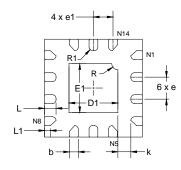
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

APRIL 2022 – REV.A to REV.A.1	Page
Update Evaluation Board Layout section	5
	_
Changes from Original (JANUARY 2022) to REV.A	Page
Changed from product preview to production data	All

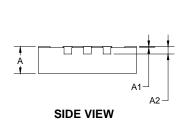
PACKAGE OUTLINE DIMENSIONS UTQFN-2×2-14L

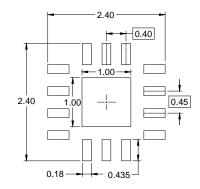






BOTTOM VIEW





RECOMMENDED LAND PATTERN (Unit: mm)

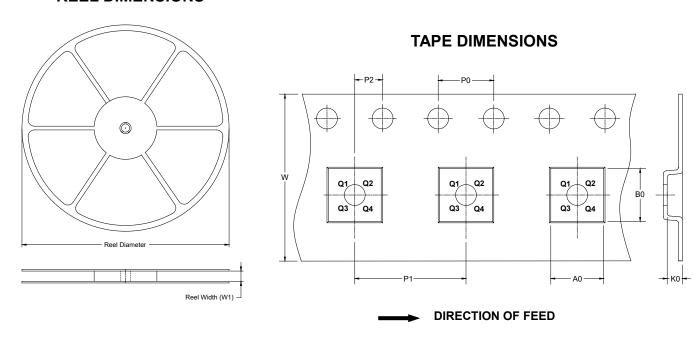
Cumb al	Dir	ers				
Symbol	MIN	MOD	MAX			
А	0.50	0.55	0.60			
A1	0.00	0.02	0.05			
A2		0.15 REF				
b	0.13	0.18	0.23			
D	1.90	2.00	2.10			
Е	1.90	2.00	2.10			
D1	0.90	1.00	1.10			
E1	0.90	1.00	1.10			
е	0.40	0.45	0.50			
e1	0.35	0.40	0.45			
k	0.15	-	-			
L	0.185	0.235	0.285			
L1	0.118 REF					
R		0.125 REF				
R1	0.075	-	-			

NOTE: This drawing is subject to change without notice.



TAPE AND REEL INFORMATION

REEL DIMENSIONS

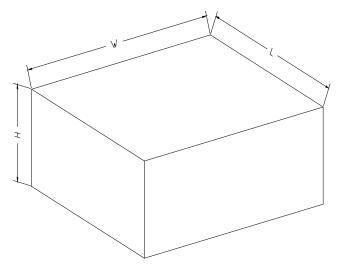


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
UTQFN-2×2-14L	7"	9.5	2.25	2.25	0.75	4.0	4.0	2.0	8.0	Q1

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18